# BDW83C

## NPN power Darlington transistor

### **Features**

- High current capability
- Fast switching speed
- High DC current gain

### **Applications**

Linear and switching industrial equipment

### Description

The BDW83C is an epitaxial-base NPN power monolithic Darlington transistor mounted in TO-247 plastic package. It is intended for use in power linear and switching applications.

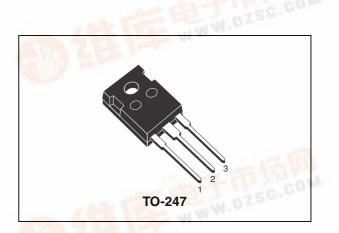


Figure 1. Internal schematic diagram

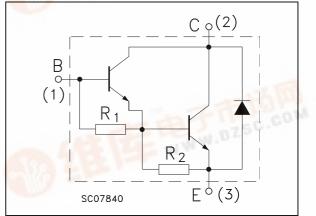


Table 1. Device sumn	nary		the second
Order code	Marking	Package	Packaging
BDW83C	BDW83C	TO-247	Tube



## 1 Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> = 0)	100	V
$V_{CEO}$	Collector-emitter voltage $(I_B = 0)$	100	V
$V_{\text{EBO}}$	Emitter-base voltage ( $I_{\rm C} = 0$ )	5	V
Ι <sub>C</sub>	Collector current	15	A
I <sub>CM</sub>	Collector peak current (t <sub>p</sub> < 5ms)	40	А
Ι <sub>Β</sub>	Base current	0.5	А
P <sub>TOT</sub>	Total dissipation at $T_c \le 25 \text{ °C}$	130	W
T <sub>stg</sub>	Storage temperature	-65 to 150	°C
ТJ	Max. operating junction temperature	150	°C

Table 2.	Absolute maximun	n ratings

### Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thj-case</sub>	Thermal resistance junction-case max	0.96	°C/W

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## 2 Electrical characteristics

( $T_{case} = 25^{\circ}C$ ; unless otherwise specified)

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Symbol	Parameter	Test co	onditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = 100 V V <sub>CB</sub> = 100 V	T <sub>C</sub> = 150°C			500 5	μA mA
I <sub>CEO</sub>	Collector cut-off current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 40 V				1	mA
I <sub>EBO</sub>	Emitter cut-off current $(I_{\rm C} = 0)$	V <sub>EB</sub> = 5 V				2	mA
V <sub>CEO(sus)</sub> <sup>(1)</sup>	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 30 mA		100			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	I <sub>C</sub> = 6 A I <sub>C</sub> = 15 A	I <sub>B</sub> = 12 mA I <sub>B</sub> = 150 mA			2.5 4	V V
V <sub>BE(on)</sub> <sup>(1)</sup>	Base-emitter on voltage	I <sub>C</sub> = 6 A	$V_{CE} = 3 V$			2.5	V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	I <sub>C</sub> = 6 A I <sub>C</sub> = 15 A		750 100		20000	
V <sub>F</sub>	Diode forward voltage	I <sub>F</sub> = 10 A				4	V
t <sub>on</sub> t <sub>off</sub>	Resistive load Turn-on time Turn-off time	$V_{CC} = 30 V$ $I_{B1} = -I_{B2} = 40$			0.9 6		μs μs

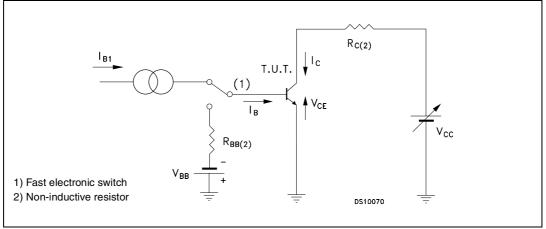
Table 4.	Electrical	characteristics
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1. Pulsed duration = 300  $\mu$ s, duty cycle  $\leq$ 1.5%.

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### 2.1 Test circuit



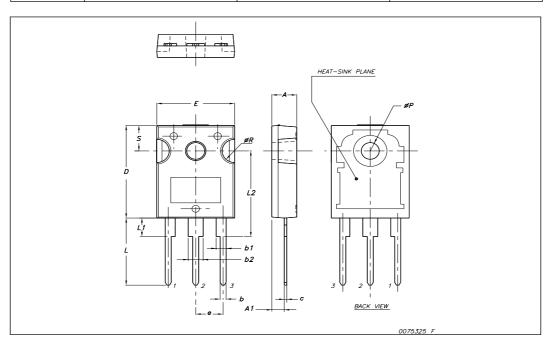


## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



	TO-247 Mechanical data		
Dim.		mm.	1
	Min.	Тур	Max.
А	4.85		5.15
A1	2.20		2.60
b	1.0		1.40
b1	2.0		2.40
b2	3.0		3.40
С	0.40		0.80
D	19.85		20.15
E	15.45		15.75
е		5.45	
L	14.20		14.80
L1	3.70		4.30
L2		18.50	
øР	3.55		3.65
øR	4.50		5.50
S		5.50	





## 4 Revision history

Date	Revision	Changes
02-Jan-2000	4	
16-Nov-2007	5	Package change from TO-218 to TO-247.



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